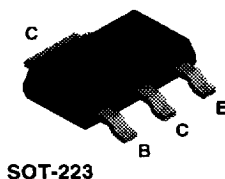


BCP52



PNP General Purpose Amplifier

This device is designed for general purpose medium power amplifiers and switching circuits requiring collector currents to 1.0 A. Sourced from Process 78.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	60	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EB0}	Emitter-Base Voltage	5.0	V
I _C	Collector Current - Continuous	1.2	A
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		BCP52	
P _D	Total Device Dissipation Derate above 25°C	1.5 12	W mW/°C
R _{θJA}	Thermal Resistance, Junction to Ambient	83.3	°C/W

PNP General Purpose Amplifier

(continued)

Electrical Characteristics

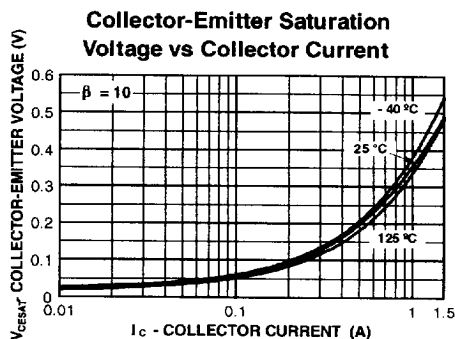
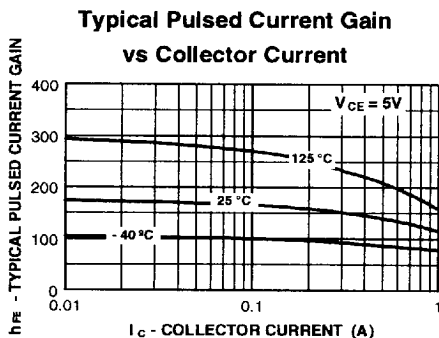
$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 10\text{ mA}, I_B = 0$	60		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 100\text{ }\mu\text{A}, I_E = 0$	60		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10\text{ }\mu\text{A}, I_C = 0$	5.0		V
I_{CBO}	Collector-Cutoff Current	$V_{CB} = 30\text{ V}, I_E = 0$		100	nA
		$V_{CB} = 30\text{ V}, I_E = 0, T_A = 125^\circ\text{C}$		10	μA
I_{EBO}	Emitter-Cutoff Current	$V_{EB} = 5.0\text{ V}, I_C = 0$		10	μA

ON CHARACTERISTICS

h_{FE}	DC Current Gain	$I_C = 5.0\text{ mA}, V_{CE} = 2.0\text{ V}$ $I_C = 150\text{ mA}, V_{CE} = 2.0\text{ V}$ $I_C = 500\text{ mA}, V_{CE} = 2.0\text{ V}$	25 40 25	250	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 500\text{ mA}, I_B = 50\text{ mA}$		0.5	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = 500\text{ mA}, V_{CE} = 2.0\text{ V}$		1.0	V

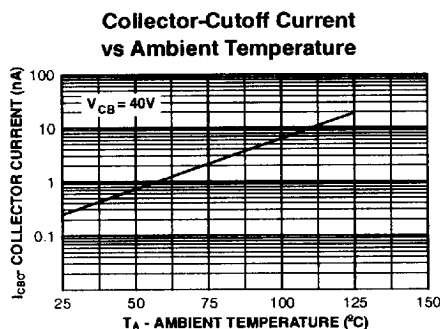
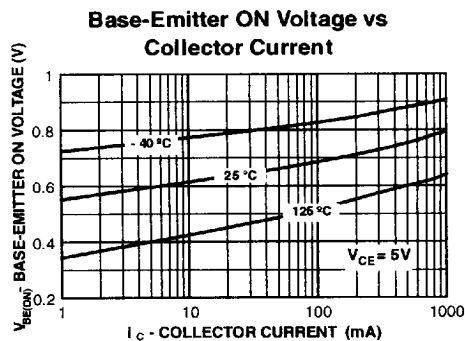
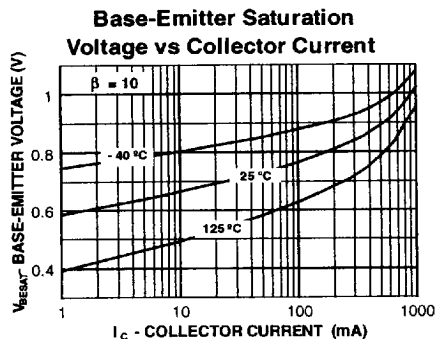
DC Typical Characteristics



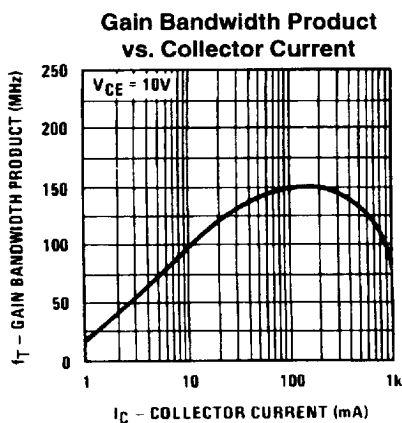
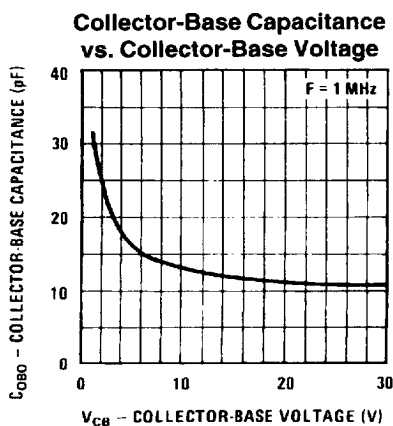
PNP General Purpose Amplifier

(continued)

DC Typical Characteristics (continued)



AC Typical Characteristics



AC Typical Characteristics (continued)

